



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



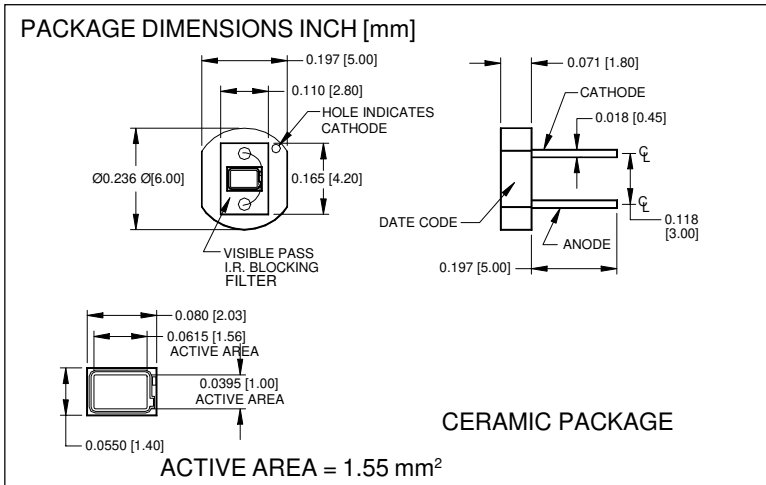
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FEATURES

- Visible response
- Low dark current
- Good linearity
- Low noise

DESCRIPTION

The **PDV-V419** is a silicon PIN photodiode, with a built in visible pass, I.R. blocking optical filter. Housed in a black ceramic package with two leads. Designed for photovoltaic operation with 0 volt bias.

APPLICATIONS

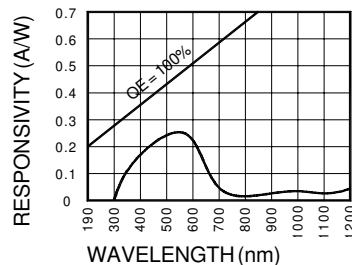
- Camera exposure meter
- Light meters
- Visible detector

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		10	V
T _{STG}	Storage Temperature	-20	+80	°C
T _O	Operating Temperature Range	-20	+60	°C
T _S	Soldering Temperature*		+240	°C
I _L	Light Current		0.5	mA

*1/16 inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{SC}	Short Circuit Current	H = 100 fc, 2850 K	2	2.8		μA
I _D	Dark Current	H = 0, V _R = 10 V		75	150	pA
R _{SH}	Shunt Resistance	H = 0, V _R = 10 mV	1.5	2.0		GΩ
TC R _{SH}	R _{SH} Temp. Coefficient	H = 0, V _R = 10 mV		-8		% / °C
C _J	Junction Capacitance	H = 0, V _R = 0 V**		500	600	pF
λ _{range}	Spectral Application Range	Spot Scan	320		730	nm
λ _p	Spectral Response - Peak	Spot Scan		560		nm
V _{BR}	Breakdown Voltage	I = 10 μA	10	15		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		3x10 ⁻¹⁴		W/√Hz
tr	Response Time	RL = 1 KΩ V _R = 10 V		500		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. **f = 1 MHz